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Team Nexperia

74HC1G32; 74HCT1G32
2-input OR gate

Rev. 05 — 14 March 2008   **Product data sheet**

1. General description

74HC1G32 and 74HCT1G32 are high-speed Si-gate CMOS devices. They provide a 2-input OR function.

The HC device has CMOS input switching levels and supply voltage range 2 V to 6 V.

The HCT device has TTL input switching levels and supply voltage range 4.5 V to 5.5 V.

The standard output currents are half those of the 74HC32 and 74HCT32.

2. Features

- Symmetrical output impedance
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- SOT353-1 and SOT753 package options

3. Ordering information

Table 1.   **Ordering information**

Type number	Package			
	Temperature range	Name	Description	Version
74HC1G32GW	−40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1
74HCT1G32GW				
74HC1G32GV	−40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753
74HCT1G32GV				

4. Marking

Table 2.   **Marking codes**

Type number	Marking code
74HC1G32GW	HG
74HCT1G32GW	TG
74HC1G32GV	H32
74HCT1G32GV	T32

founded by Philips
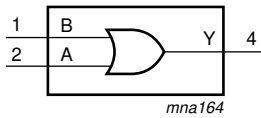
5. Functional diagram

Fig 1. Logic symbol
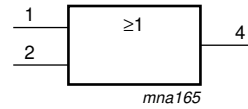
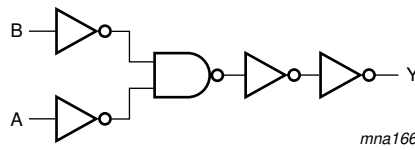**Fig 2. IEC logic symbol**

Fig 3. Logic diagram

6. Pinning information

6.1 Pinning
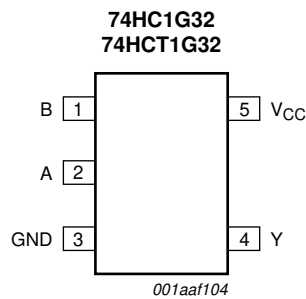
Fig 4. Pin configuration

6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
B	1	data input B
A	2	data input A
GND	3	ground (0 V)
Y	4	data output Y
V_{CC}	5	supply voltage

7. Functional description

Table 4.   Function table
H = HIGH voltage level; L = LOW voltage level

Inputs		Output
A	**B**	**Y**
L	L	L
L	H	H
H	L	H
H	H	H

8. Limiting values

Table 5.   Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V). [1]

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		−0.5	+7.0	V
I_{IK}	input clamping current	$V_I < -0.5$ V or $V_I > V_{CC} + 0.5$ V	-	±20	mA
I_{OK}	output clamping current	$V_O < -0.5$ V or $V_O > V_{CC} + 0.5$ V	-	±20	mA
I_O	output current	-0.5 V $< V_O < V_{CC} + 0.5$ V	-	±12.5	mA
I_{CC}	supply current		-	25	mA
I_{GND}	ground current		−25	-	mA
T_{stg}	storage temperature		−65	+150	°C
P_{tot}	total power dissipation	$T_{amb} = -40$ °C to +125 °C [2]	-	200	mW

[1]   The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2]   Above 55 °C the value of P_{tot} derates linearly with 2.5 mW/K.

9. Recommended operating conditions

Table 6.   Recommended operating conditions
Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	74HC1G32			74HCT1G32			Unit
			Min	**Typ**	**Max**	**Min**	**Typ**	**Max**	
V_{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
V_I	input voltage		0	-	V_{CC}	0	-	V_{CC}	V
V_O	output voltage		0	-	V_{CC}	0	-	V_{CC}	V
T_{amb}	ambient temperature		−40	+25	+125	−40	+25	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 2.0$ V	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5$ V	-	-	139	-	-	139	ns/V
		$V_{CC} = 6.0$ V	-	-	83	-	-	-	ns/V

74HC_HCT1G32_5

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10. Static characteristics

Table 7.   Static characteristics

Voltages are referenced to GND (ground = 0 V). All typical values are measured at T_{amb} = 25 °C.

Symbol	Parameter	Conditions	−40 °C to +85 °C			−40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	
74HC1G32								
V_{IH}	HIGH-level input voltage	V_{CC} = 2.0 V	1.5	1.2	-	1.5	-	V
		V_{CC} = 4.5 V	3.15	2.4	-	3.15	-	V
		V_{CC} = 6.0 V	4.2	3.2	-	4.2	-	V
V_{IL}	LOW-level input voltage	V_{CC} = 2.0 V	-	0.8	0.5	-	0.5	V
		V_{CC} = 4.5 V	-	2.1	1.35	-	1.35	V
		V_{CC} = 6.0 V	-	2.8	1.8	-	1.8	V
V_{OH}	HIGH-level output voltage	V_I = V_{IH} or V_{IL}						
		I_O = −20 µA; V_{CC} = 2.0 V	1.9	2.0	-	1.9	-	V
		I_O = −20 µA; V_{CC} = 4.5 V	4.4	4.5	-	4.4	-	V
		I_O = −20 µA; V_{CC} = 6.0 V	5.9	6.0	-	5.9	-	V
		I_O = −2.0 mA; V_{CC} = 4.5 V	4.13	4.32	-	3.7	-	V
		I_O = −2.6 mA; V_{CC} = 6.0 V	5.63	5.81	-	5.2	-	V
V_{OL}	LOW-level output voltage	V_I = V_{IH} or V_{IL}						
		I_O = 20 µA; V_{CC} = 2.0 V	-	0	0.1	-	0.1	V
		I_O = 20 µA; V_{CC} = 4.5 V	-	0	0.1	-	0.1	V
		I_O = 20 µA; V_{CC} = 6.0 V	-	0	0.1	-	0.1	V
		I_O = 2.0 mA; V_{CC} = 4.5 V	-	0.15	0.33	-	0.4	V
		I_O = 2.6 mA; V_{CC} = 6.0 V	-	0.16	0.33	-	0.4	V
I_I	input leakage current	V_I = V_{CC} or GND; V_{CC} = 6.0 V	-	-	1.0	-	1.0	µA
I_{CC}	supply current	V_I = V_{CC} or GND; I_O = 0 A; V_{CC} = 6.0 V	-	-	10	-	20	µA
C_I	input capacitance		-	1.5	-	-	-	pF
74HCT1G32								
V_{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	V
V_{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	V
V_{OH}	HIGH-level output voltage	V_I = V_{IH} or V_{IL}; V_{CC} = 4.5 V						
		I_O = −20 µA	4.4	4.5	-	4.4	-	V
		I_O = −2.0 mA	4.13	4.32	-	3.7	-	V
V_{OL}	LOW-level output voltage	V_I = V_{IH} or V_{IL}; V_{CC} = 4.5 V						
		I_O = 20 µA	-	0	0.1	-	0.1	V
		I_O = 2.0 mA	-	0.15	0.33	-	0.4	V
I_I	input leakage current	V_I = V_{CC} or GND; V_{CC} = 5.5 V	-	-	1.0	-	1.0	µA

Table 7. **Static characteristics** *…continued*

Voltages are referenced to GND (ground = 0 V). All typical values are measured at T_{amb} = 25 °C.

Symbol	Parameter	Conditions	−40 °C to +85 °C			−40 °C to +125 °C		Unit
			Min	**Typ**	**Max**	**Min**	**Max**	
I_{CC}	supply current	V_I = V_{CC} or GND; I_O = 0 A; V_{CC} = 5.5 V	-	-	10	-	20	µA
ΔI_{CC}	additional supply current	per input; V_{CC} = 4.5 V to 5.5 V; V_I = V_{CC} − 2.1 V; I_O = 0 A	-	-	500	-	850	µA
C_I	input capacitance		-	1.5	-	-	-	pF

11. Dynamic characteristics

Table 8. **Dynamic characteristics**

GND = 0 V; t_r = t_f ≤ 6.0 ns. All typical values are measured at T_{amb} = 25 °C. For test circuit see Figure 6

Symbol	Parameter	Conditions		−40 °C to +85 °C			−40 °C to +125 °C		Unit
				Min	**Typ**	**Max**	**Min**	**Max**	
74HC1G32									
t_{pd}	propagation delay	A and B to Y; see Figure 5	[1]						
		V_{CC} = 2.0 V; C_L = 50 pF		-	18	115	-	135	ns
		V_{CC} = 4.5 V; C_L = 50 pF		-	8	23	-	27	ns
		V_{CC} = 5.0 V; C_L = 15 pF		-	8	-	-	-	ns
		V_{CC} = 6.0 V; C_L = 50 pF		-	7	20	-	23	ns
C_{PD}	power dissipation capacitance	V_I = GND to V_{CC}	[2]	-	19	-	-	-	pF
74HCT1G32									
t_{pd}	propagation delay	A and B to Y; see Figure 5	[1]						
		V_{CC} = 4.5 V; C_L = 50 pF		-	10	24	-	27	ns
		V_{CC} = 5.0 V; C_L = 15 pF		-	10	-	-	-	ns
C_{PD}	power dissipation capacitance	V_I = GND to V_{CC} − 1.5 V	[2]	-	20	-	-	-	pF

[1] t_{pd} is the same as t_{PLH} and t_{PHL}.

[2] C_{PD} is used to determine the dynamic power dissipation P_D (µW).

  $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

  f_i = input frequency in MHz

  f_o = output frequency in MHz

  C_L = output load capacitance in pF

  V_{CC} = supply voltage in V

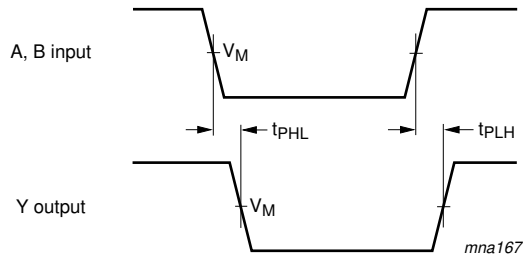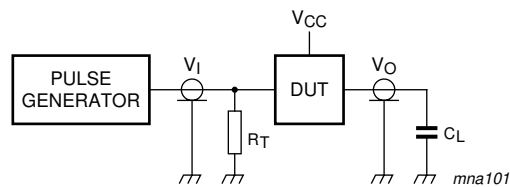 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs

12. Waveforms

Fig 5. The input (A and B) to output (Y) propagation delays

Measurement points are given in Table 8. Definitions for test circuit:

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

Fig 6. Load circuitry for switching times

13. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm   **SOT353-1**
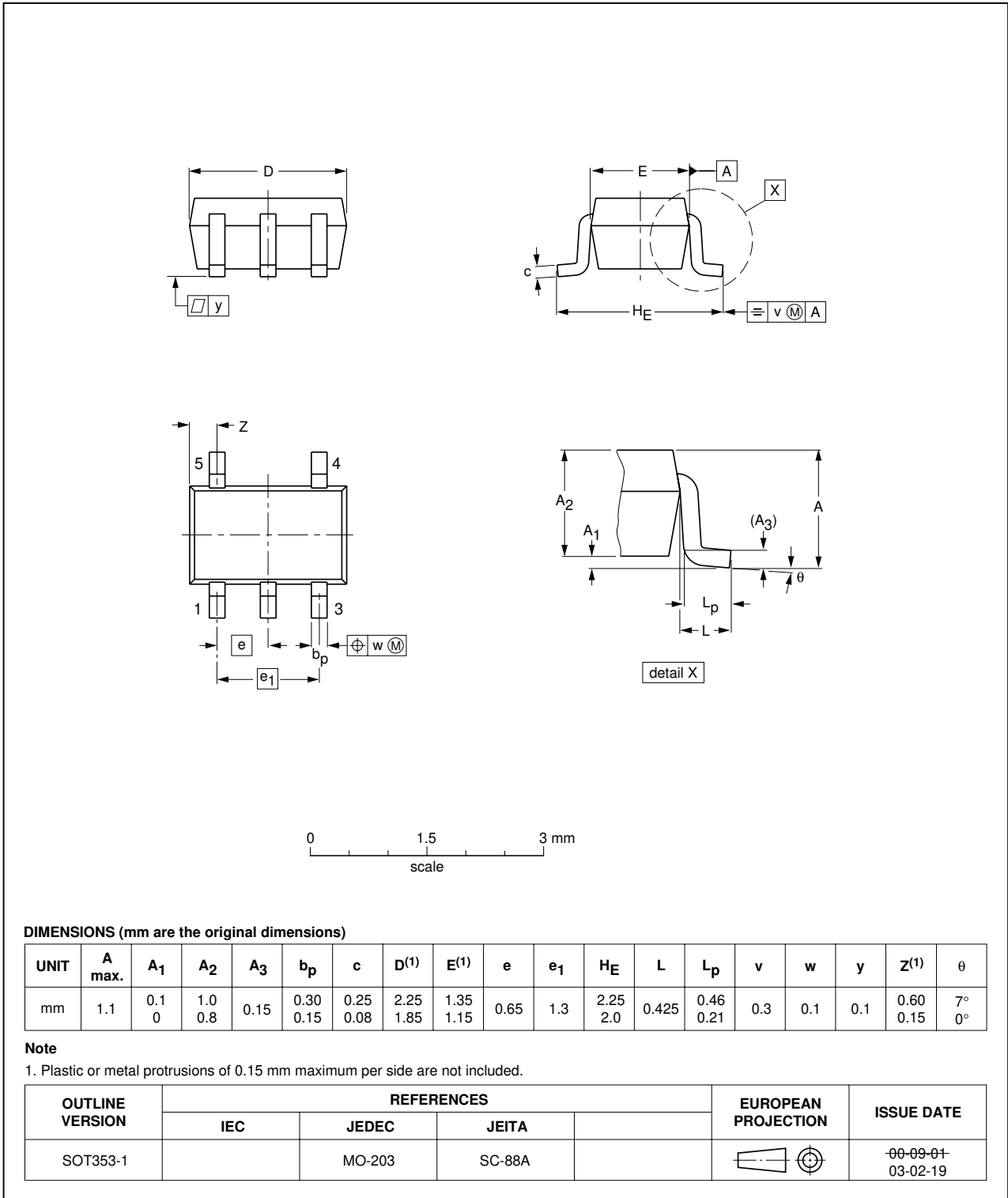
D

y

E

A

X

c

H_E

Z

5   4

1   3

e

b_p

w Ⓜ

e_1

A_2

A_1

(A_3)

A

θ

L_p

L

detail X

0   1.5   3 mm

scale

DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A_1	A_2	A_3	b_p	c	D[1]	E[1]	e	e_1	H_E	L	L_p	v	w	y	Z[1]	θ
mm	1.1	0.1 0	1.0 0.8	0.15	0.30 0.15	0.25 0.08	2.25 1.85	1.35 1.15	0.65	1.3	2.25 2.0	0.425	0.46 0.21	0.3	0.1	0.1	0.60 0.15	7° 0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT353-1		MO-203	SC-88A			~~00-09-01~~ 03-02-19

Fig 7.   Package outline SOT353-1 (TSSOP5)

74HC_HCT1G32_5

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Plastic surface-mounted package; 5 leads   **SOT753**

DIMENSIONS (mm are the original dimensions)

UNIT	A	A$_1$	b$_p$	c	D	E	e	H$_E$	L$_p$	Q	v	w	y
mm	1.1 0.9	0.100 0.013	0.40 0.25	0.26 0.10	3.1 2.7	1.7 1.3	0.95	3.0 2.5	0.6 0.2	0.33 0.23	0.2	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT753			SC-74A			~~02-04-16~~ 06-03-16
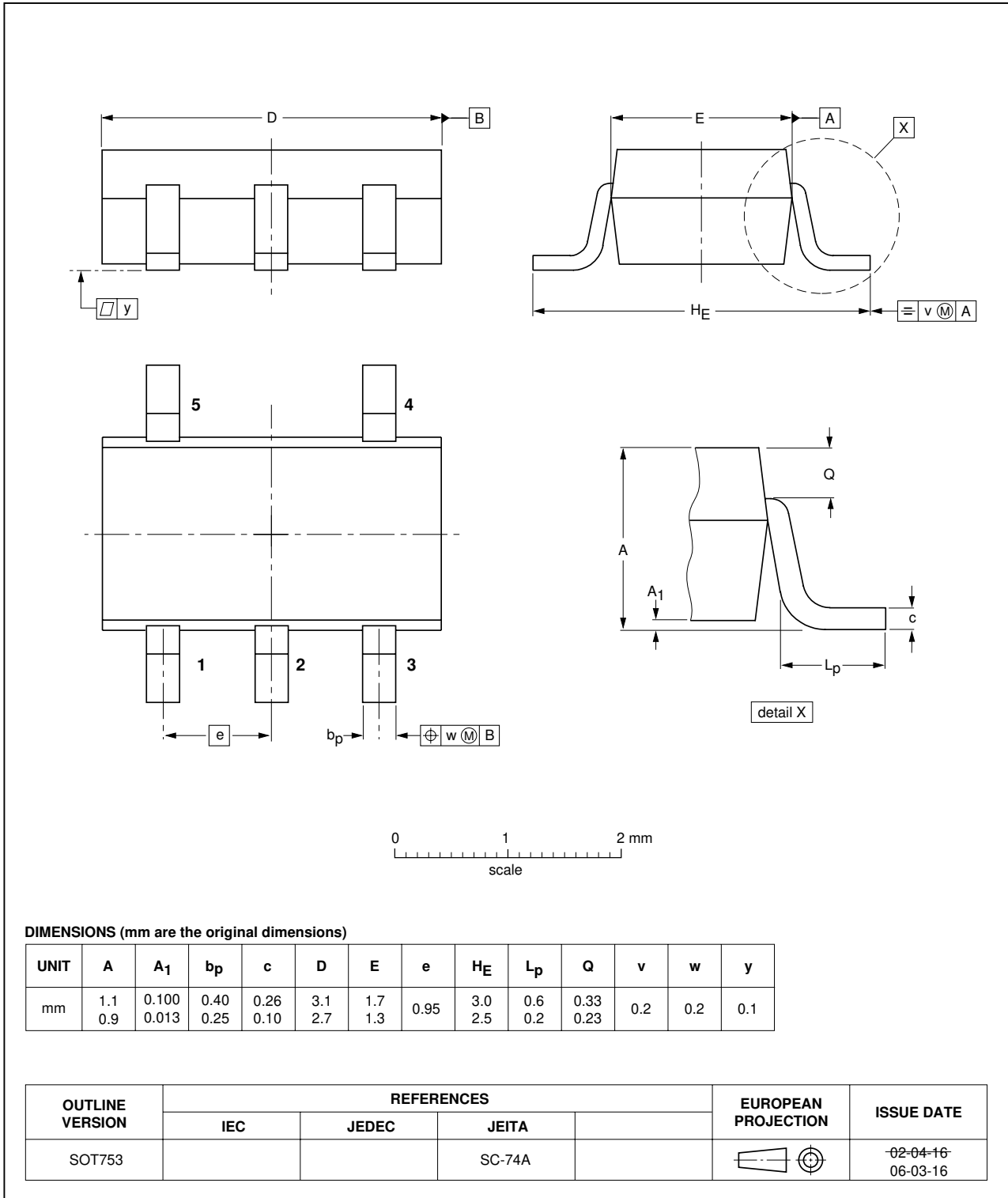
Fig 8. Package outline SOT753 (SC-74A)

14. Abbreviations

Table 9.   Abbreviations

Acronym	Description
DUT	Device Under Test
TTL	Transistor-Transistor Logic

15. Revision history

Table 10.   Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT1G32_5	20080314	Product data sheet	-	74HC_HCT1G32_4
Modifications:		• Pin description of Pin 4 changed from input to output in Table 3.		
74HC_HCT1G32_4	20070514	Product data sheet	-	74HC_HCT1G32_3
74HC_HCT1G32_3	20020515	Product specification	-	74HC_HCT1G32_2
74HC_HCT1G32_2	20010406	Product specification	-	74HC_HCT1G32
74HC_HCT1G32	19971216	Preliminary specification	-	-

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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74HC_HCT1G32_5

Product data sheet

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